

MJL21194G

<u>RFO</u>

Data Sheet

Bipolar Transistors - BJT 16A 250V 200W NPN

Manufacturers	ON Semiconductor, LLC
Package/Case	TO-264
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for MJL21194G or Email to us: sales@ovaga.com We will contact you in 12 hours.
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General Description

The MJL21193 and MJL21194 Bipolar Complementary Audio Power Transistors utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and other linear applications.

Features

Excellent Gain Linearity

Accurate reproduction of input signal

High SOA: 2.25 A, 80 V, 1 Second

Reliable performance at higher powers

Total Harmonic Distortion Characterized

High DC Current Gain - = 8 Adc

Application

ONSEMI



Related Products



<u>MJE172</u> ON Semiconductor, LLC TO-126



MJD42CT4G ON Semiconductor, LLC SOT25



MJL21195G

ON Semiconductor, LLC TO-3PL



<u>MJ4502G</u> ON Semiconductor, LLC TO-204-2 (TO-3)





MJD44H11-1G ON Semiconductor, LLC TO-251

ON Semiconductor, LLC

MJ802G

MJE350G

TO-126

ON Semiconductor, LLC TO-204-2

MJH6287



ON Semiconductor, LLC TO-247